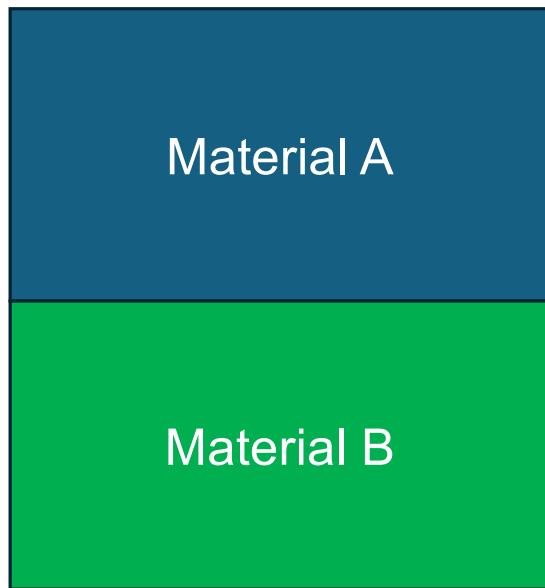


# Acoustic and Diffuse Mismatch Model

Yucheng Yang

<https://github.com/micromechanic/InterfacialPhononTransport>

# Thermal boundary conductance



## Scenario:

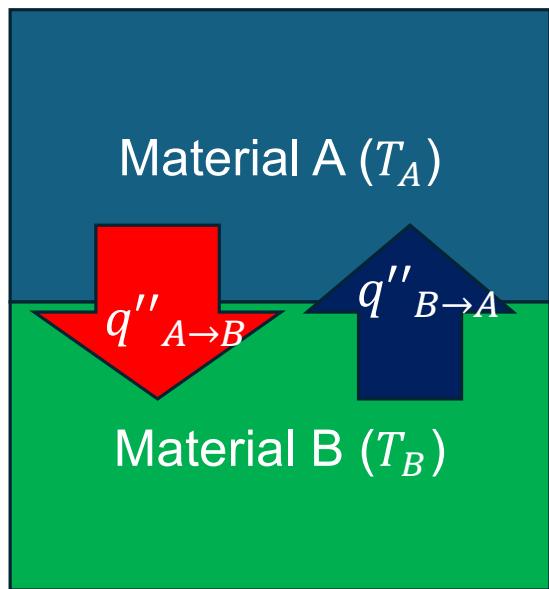
1. Material A is conformal deposited onto Materials:  
Thermal boundary conductance is due to material mismatch rather than voids.
2. Material A is sitting at  $T_A$  and Material B is sitting at  $T_B$ . At the interface, the difference between  $T_A$  and  $T_B$  is small.

**Question:** what is the thermal boundary conductance at the interface between Material A and Material B?

## Thermal boundary resist:

- Voids
- Material mismatch

# Definition of thermal boundary conductance



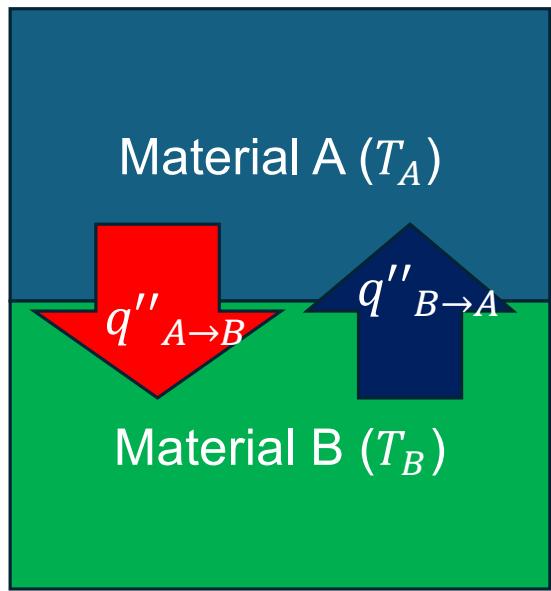
**Net heat current density** ( $q''$  has a unit of  $\text{W m}^{-2}$ ):

$$G(T_A - T_B) = q''_{A \rightarrow B}(T_A) - q''_{B \rightarrow A}(T_B)$$

**Thermal boundary conductance:**

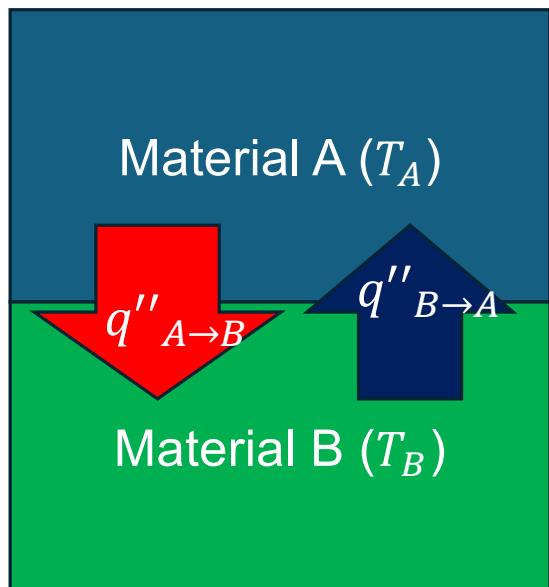
$$G = \frac{q''_{A \rightarrow B}(T_A) - q''_{B \rightarrow A}(T_B)}{T_A - T_B}$$

# Landour formalism for phononic transport



$$\begin{aligned} & q''_{A \rightarrow B}(T_A) - q''_{B \rightarrow A}(T_B) \\ &= \frac{1}{2} \sum_j \left[ \int_0^{\omega_D} \hbar \omega v_{A,j}(\omega) \tau_{A \rightarrow B,j}(\omega) f_{BE}(T_A, \omega) D_{A,j}(\omega) d\omega \right. \\ & \quad \left. - \int_0^{\omega_D} \hbar \omega v_{B,j}(\omega) \tau_{B \rightarrow A,j}(\omega) f_{BE}(T_B, \omega) D_{B,j}(\omega) d\omega \right] \end{aligned}$$

# Landour formalism for phononic transport



$$\frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j}(\omega) \tau_{A \rightarrow B,j}(\omega) f_{BE}(T_A, \omega) D_{A,j}(\omega) d\omega$$

$\hbar \omega$ : Energy of each phonons

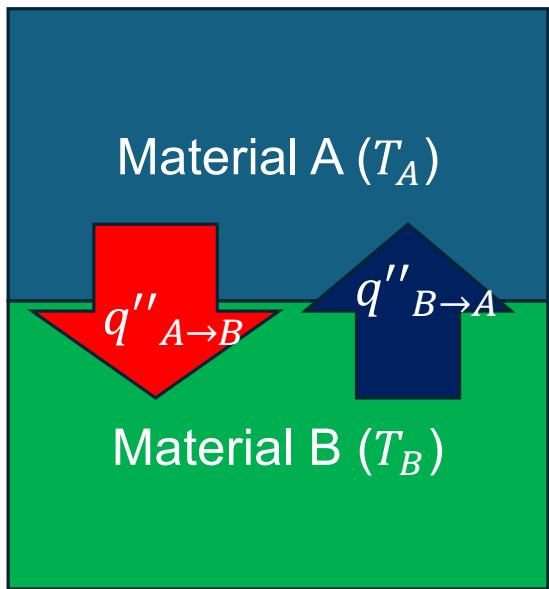
$v_{A,j}(\omega)$ : The speed of these phonons

$\tau_{A \rightarrow B,j}(\omega)$ : The probability the phonons will move from medium  $A \rightarrow B$  of mode  $j$ .

$f_{BE}(T_A, \omega)$ : The distribution of phonon population.

$D_{A,j}(\omega)$ : The density of phonons at each state.

# Simplifications

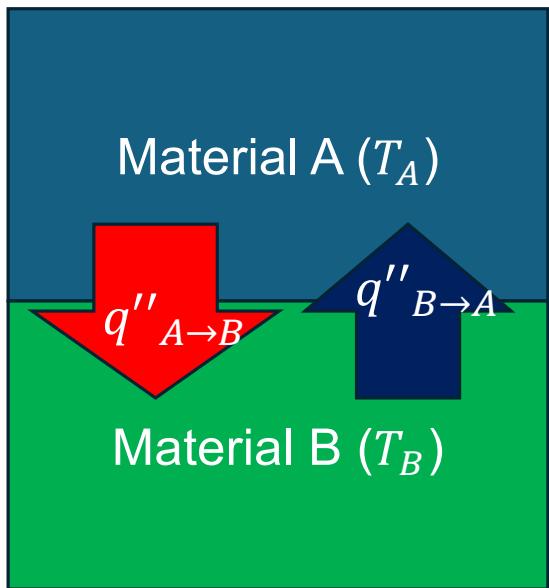


$$\begin{aligned} & q''_{A \rightarrow B}(T_A) - q''_{B \rightarrow A}(T_B) \\ &= \frac{1}{2} \sum_j \left[ \int_0^{\omega_D} \hbar \omega v_{A,j}(\omega) \tau_{A \rightarrow B,j}(\omega) f_{BE}(T_A, \omega) D_{A,j}(\omega) d\omega \right. \\ & \quad \left. - \int_0^{\omega_D} \hbar \omega v_{B,j}(\omega) \tau_{B \rightarrow A,j}(\omega) f_{BE}(T_B, \omega) D_{B,j}(\omega) d\omega \right] \end{aligned}$$

$$T_A = T_B:$$

$$\begin{aligned} v_{A,j}(\omega) \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) &= \\ v_{B,j}(\omega) \tau_{B \rightarrow A,j}(\omega) D_{B,j}(\omega) \end{aligned}$$

# Simplified Landour formalism

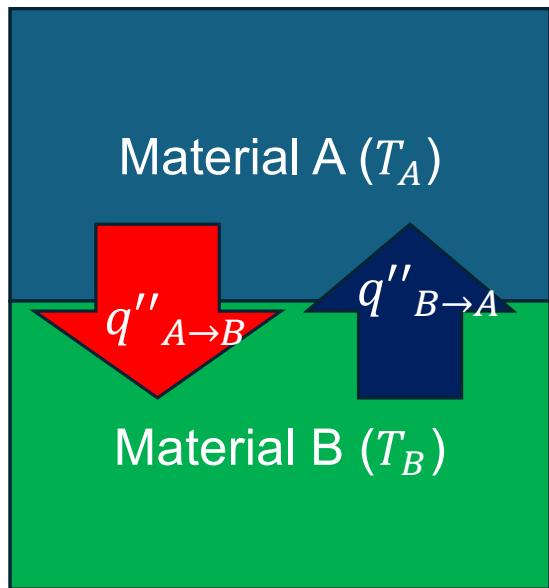


$$q''_{A \rightarrow B}(T_A) - q''_{B \rightarrow A}(T_B) = \frac{1}{2} \sum_j \left[ \int_0^{\omega_D} \hbar \omega v_{A,j}(\omega) \tau_{A \rightarrow B,j}(\omega) f_{BE}(T_A, \omega) D_{A,j}(\omega) d\omega \right. \\ \left. - \int_0^{\omega_D} \hbar \omega v_{B,j}(\omega) \tau_{B \rightarrow A,j}(\omega) f_{BE}(T_B, \omega) D_{B,j}(\omega) d\omega \right]$$



$$q''_{A \rightarrow B}(T_A) - q''_{A \rightarrow B}(T_B) = \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) [f_{BE}(T_A, \omega) \\ - f_{BE}(T_B, \omega)] d\omega$$

# Phononic window



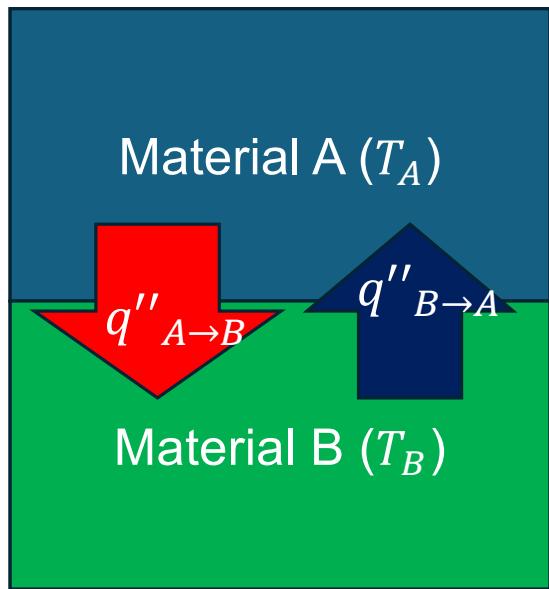
$$q''_{A \rightarrow B}(T_A) - q''_{A \rightarrow B}(T_B) \\ = \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) [f_{BE}(T_A, \omega) \\ - f_{BE}(T_B, \omega)] d\omega$$

Assume the difference between  $T_A$  and  $T_B$  is small:

$$f_{BE}(T_A, \omega) - f_{BE}(T_B, \omega) = f_{BE}(T_A, \omega) - f_{BE}(T_A - \Delta T, \omega)$$

$$f_{BE}(T_A, \omega) - f_{BE}(T_B, \omega) = \frac{\partial f_{BE}(T_A, \omega)}{\partial T} \Delta T$$

# Thermal boundary conductance equation



$$\begin{aligned}
 & q''_{A \rightarrow B}(T_A) - q''_{A \rightarrow B}(T_B) \\
 &= \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) [f_{BE}(T_A, \omega) \\
 & \quad - f_{BE}(T_B, \omega)] d\omega \\
 & q''_{A \rightarrow B}(T_A) - q''_{A \rightarrow B}(T_B) \\
 &= \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) \frac{\partial f_{BE}(T_A, \omega)}{\partial T} \Delta T d\omega
 \end{aligned}$$

Review of Modern Physics, Vol.61, No. 3, July 1989

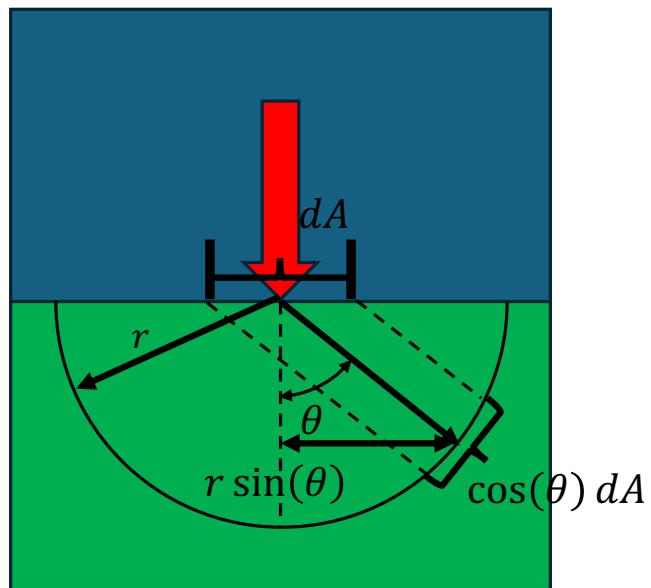
**Equation for thermal conductance:**

$$G = \frac{q''_{A \rightarrow B}(T_A) - q''_{A \rightarrow B}(T_B)}{T_A - T_B} = \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) \frac{\partial f_{BE}(T_A, \omega)}{\partial T} d\omega$$

# Mismatch Models

$$G = \frac{\dot{q}}{\Delta T} = \frac{1}{2} \sum_j \int_0^{\omega_D} \hbar \omega v_{A,j} \tau_{A \rightarrow B,j}(\omega) D_{A,j}(\omega) \frac{\partial f_{BE}(T_A, \omega)}{\partial T} d\omega$$

We know everything, except  $\tau_{A \rightarrow B,j}(\omega)$ .



Average transmission coefficient:

$$\tau_{A \rightarrow B,j}(\omega) = \int_0^{\pi/2} \alpha_{A \rightarrow B,j}(\omega, \theta) \cos(\theta) \sin(\theta) d\theta$$

$\alpha_{A \rightarrow B,j}(\omega, \theta)$ : angle dependent transmission coefficient.  
 $\cos(\theta)$ : from the projected area.  
 $\sin(\theta)$ : from the spherical integral

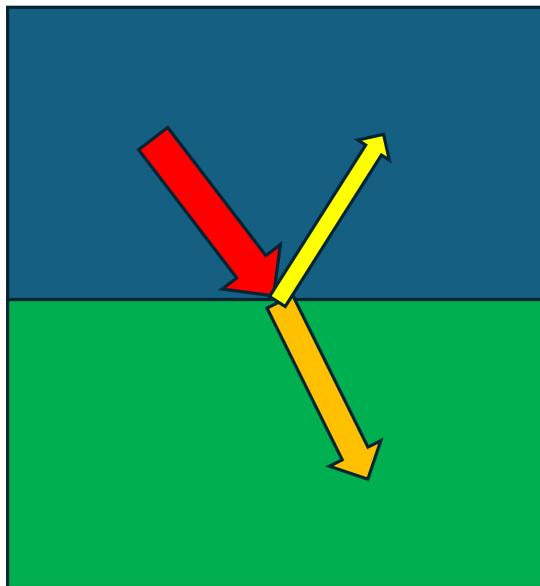
# Regimes where AMM and DMM is applicable

$$\alpha_{A \rightarrow B,j}(\omega, \theta)$$

Interface roughness is very small compared to the De Broglie wavelength of the phonons.

**$T$  is small.**

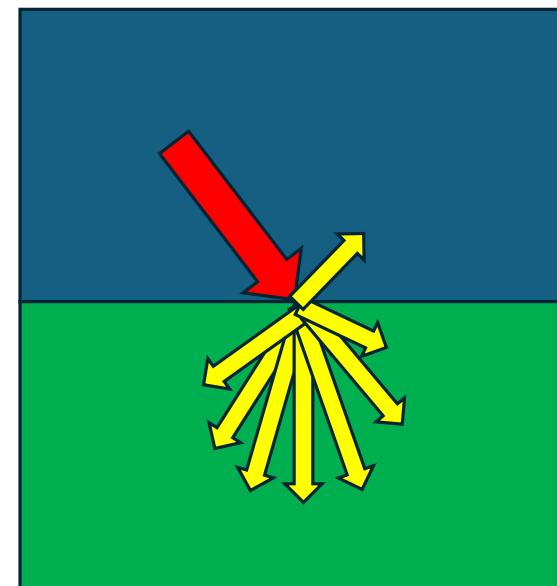
**Acoustic Mismatch Model (AMM):**



Interface roughness is very large compared to the De Broglie wavelength of the phonons.

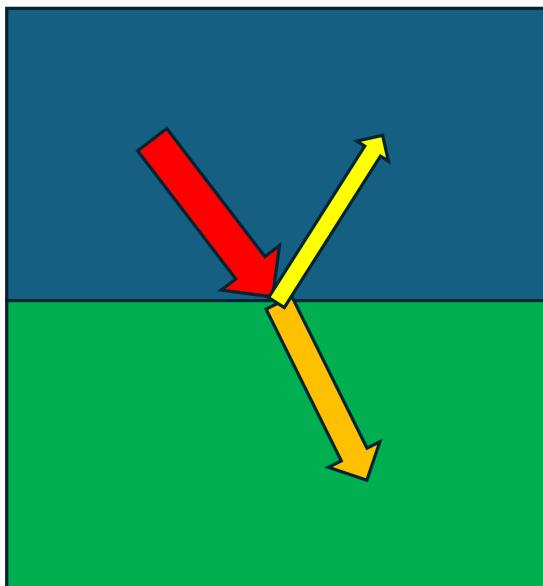
**$T$  is large.**

**Diffuse Mismatch Model (DMM):**



# Highly simplified scenario for AMM

**Acoustic Mismatch Model (AMM):**



- Do not allow mode conversion. Transverse mode stay transverse. Longitudinal stay Longitudinal.
- The only angle dependence is the velocity component that is perpendicular to the interface.
- The only differences between different branches (transverse vs. longitudinal) are the speed of sound.
- No frequency dependence.

$$\alpha_{A \rightarrow B,j}(\theta_A) = \frac{4Z_A Z_B}{(Z_A + Z_B)^2}$$

Acoustic Impedance:

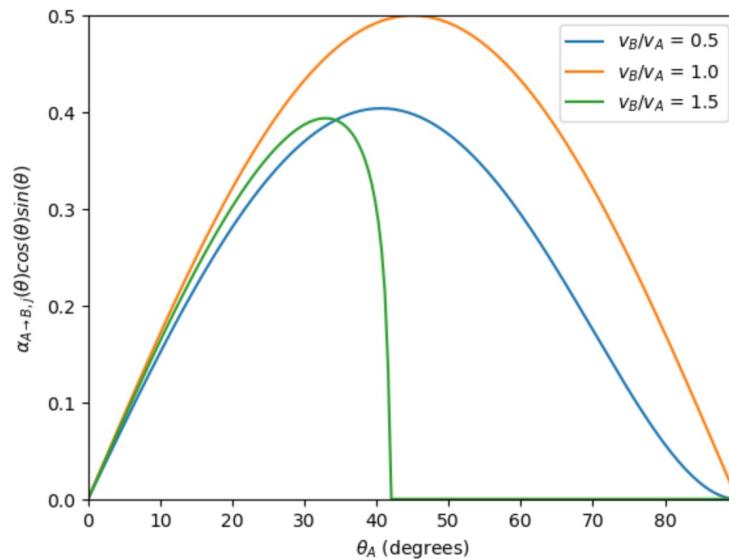
$$Z_A = \frac{\rho v_{A,j}}{\cos(\theta_A)} \quad Z_B = \frac{\rho v_{B,j}}{\cos(\theta_B)}$$

Snell's Law (relating  $\theta_A$  and  $\theta_B$ ):

$$\frac{\sin(\theta_A)}{v_{A,j}} = \frac{\sin(\theta_B)}{v_{B,j}}$$

# In side of the transmission coefficient for AMM

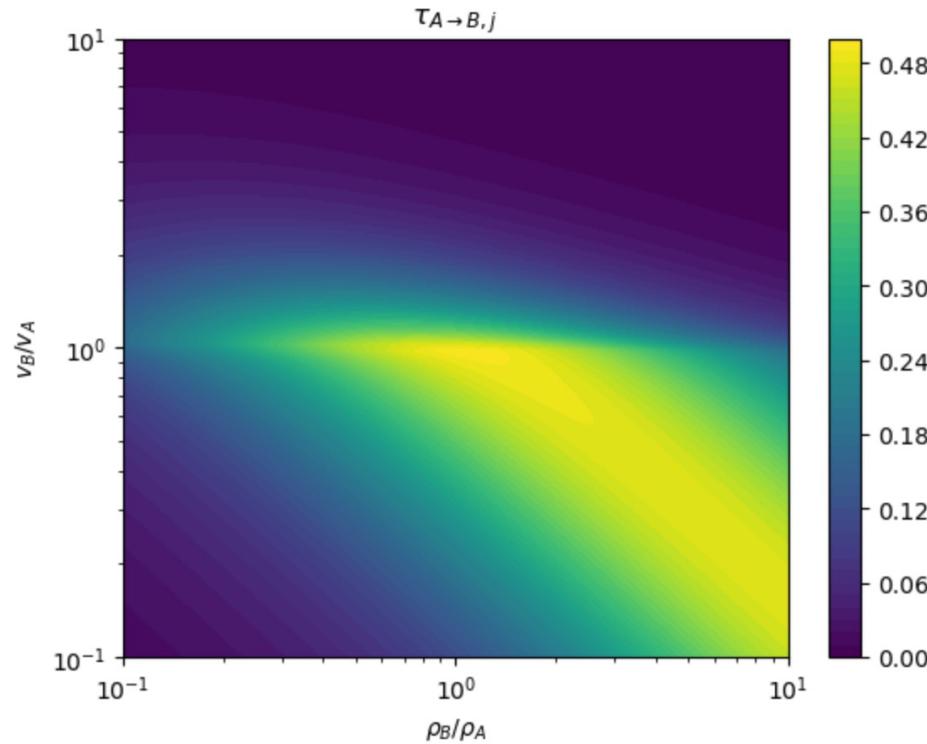
$$\alpha_{A \rightarrow B,j}(\theta) \cos(\theta) \sin(\theta)$$



By looking at the  $\alpha_{A \rightarrow B,j}(\theta) \cos(\theta) \sin(\theta)$ , it is intuitive that  $\tau_{A \rightarrow B,j}$  is the largest when  $v_b/v_A = 1$  and smallest when  $v_B/v_A = 1.5$  due to total internal reflection. The maximum  $\alpha_{A \rightarrow B,j}(\theta) \cos(\theta) \sin(\theta)$  is 0.5 for  $v_b/v_A = 1$ .

# Density and $v_g$ ratio impact on $\tau_{A \rightarrow B, j}$

$$\tau_{A \rightarrow B, j} = \int_0^{\pi/2} \alpha_{A \rightarrow B, j}(\theta) \cos(\theta) \sin(\theta) d\theta$$



Reproducing the results from: Can. J. Phys. Vol. 37 (1959)

# Solving the thermal boundary conductance

## Calculation for Thermal Boundary Conductance using AMM

since the average transmission coefficient ( $\tau_{A \rightarrow B,j}$ ) and phonon propagation velocity ( $v_{A,j}$ ) is assumed to be independent to the phonon frequency ( $\omega$ ), the previous thermal boundary conductance ( $G$ ) equation simplifies to:

$$G = \frac{1}{2} \sum_j v_{A,j} \tau_{A \rightarrow B,j} \int_0^{\omega_D} \hbar \omega D_{A,j}(\omega) \frac{\partial f_{BE}(T, \omega)}{\partial T} d\omega$$

Under Debye's assumption of linear phonon dispersion, the phonon density of state ( $D_{A,j}(\omega)$ ) is:

$$D_{A,j}(\omega) = \frac{\omega^2}{2\pi^2 v_{A,j}^3}$$

Thus,  $G$  simplifies to:

$$G = \frac{1}{4\pi^2} \left[ \frac{\tau_{A \rightarrow B,l}}{v_{A,l}^2} + \frac{2\tau_{A \rightarrow B,t}}{v_{A,t}^2} \right] \int_0^{\omega_D} \hbar \omega^3 \frac{\partial f_{BE}(T, \omega)}{\partial T} d\omega$$

# Simplify the equation to get a close formed solution

To improve numerical stability, we introduce the dimensionless variable  $x$  for  $\frac{\hbar\omega}{k_B T}$ . This substitution improves numerical stability, because it rescales the integration variable to be dimensionless and of order unity near the dominant contribution.

$$G = \frac{k_B^4 T^3}{4\pi^2 \hbar^3} \left[ \frac{\tau_{A \rightarrow B, l}}{v_{A, l}^2} + \frac{2\tau_{A \rightarrow B, t}}{v_{A, t}^2} \right] \int_0^{x_D} x^4 \frac{e^x}{(e^x - 1)^2} dx$$

There are two important observations:

1. The integral is unitless. Thus,  $G$  is positively correlated with  $T^3$ .
2. When  $T \ll \Theta_D$ ,  $x_D \rightarrow \infty$ , the integral has a solution of  $\frac{4}{15}\pi^4$ :

$$G = \frac{\pi^2 k_B^4 T^3}{15 \hbar^3} \left[ \frac{\tau_{A \rightarrow B, l}}{v_{A, l}^2} + \frac{2\tau_{A \rightarrow B, t}}{v_{A, t}^2} \right]$$

At low temperature which is the applicable regime of AMM, the  $G$  is only dependent on the  $v_A$ ,  $v_B$ ,  $\rho_A$ ,  $\rho_B$ , and  $T$ . However, at ultralow temperature ( $T < 1K$ ), the AMM model underestimates  $G$ , for more detail refer to the review paper: *Reviews of Modern Physics*, Vol. 61, No. 3, July 1989.

# Creating a database for the material properties

## AMM Thermal Boundary Conductance:

One common way to show the thermal boundary conductance is to show the T independent terms:

$$\frac{G}{T^3} = \frac{\pi^2 k_B^4}{15 \hbar^3} \left[ \frac{\tau_{A \rightarrow B, l}}{v_{A, l}^2} + \frac{2\tau_{A \rightarrow B, t}}{v_{A, t}^2} \right]$$

	material	density	v_l	v_t
0	gold	19300	3390.0	1290.0
1	quartz	2660	6090.0	4100.0
2	sapphire	3970	10890.0	6450.0
3	silicon	2330	8970.0	5332.0

### Gold to Sapphire Interface

```
T = 10; # Kelvin
g_go_sa= g_AMM(gold.v_l, sapphire.v_l, gold.v_t, sapphire.v_t, gold.density, sapphire.density)
g_go_sa_T = g_go_sa/T**3;
print(f"Gold to sapphire interface: {g_go_sa_T:.2f} W/m^2/K^4")
```

Gold to sapphire interface: 526.39 W/m^2/K^4

### Sapphire to Gold Interface

```
g_sa_go= g_AMM(sapphire.v_l, gold.v_l, sapphire.v_t, gold.v_t, sapphire.density, gold.density)
g_sa_go_T = g_sa_go/T**3;
print(f"Sapphire to gold interface: {g_sa_go_T:.2f} W/m^2/K^4")
```

Sapphire to gold interface: 526.40 W/m^2/K^4

### Gold to Quartz Interface

```
g_go_qz= g_AMM(gold.v_l, quartz.v_l, gold.v_t, quartz.v_t, gold.density, quartz.density)
g_go_qz_T = g_go_qz/T**3;
print(f"Gold to Quartz interface: {g_go_qz_T:.2f} W/m^2/K^4")
```

Gold to Quartz interface: 1327.14 W/m^2/K^4

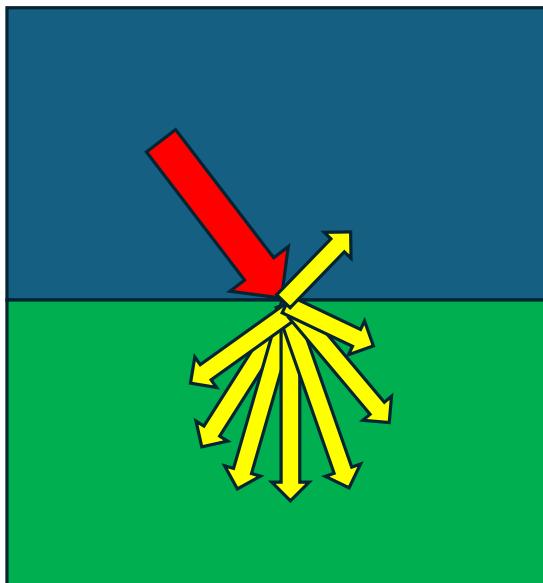
### Gold to Silicon Interface

```
g_go_si= g_AMM(gold.v_l, silicon.v_l, gold.v_t, silicon.v_t, gold.density, silicon.density)
g_go_si_T = g_go_si/T**3;
print(f"Gold to Silicon interface: {g_go_si_T:.2f} W/m^2/K^4")
```

Gold to Silicon interface: 780.96 W/m^2/K^4

# High temperature: diffuse mismatch model

## Diffuse Mismatch Model (DMM):



- The phonon does not know where the come from so  $\alpha_{A \rightarrow B, j}$  is not a function of  $\theta_A$ .
- The phonon does not know which mode it came from  $\alpha_{A \rightarrow B, j} \rightarrow \alpha_{A \rightarrow B}$ .
- We assume that there is no absorption at the boundary.

$$\alpha_{A \rightarrow B} = 1 - \alpha_{B \rightarrow A}$$

Thus, the number of phonons that leaving from A to B must equal to the phonon leaving from B to A.

$$\sum_j v_{A,j} D_{A,j} f_{BE} \alpha_{A \rightarrow B} = \sum_j v_{B,j} D_{B,j} f_{BE} (1 - \alpha_{A \rightarrow B})$$

We can solve for  $\alpha_{A \rightarrow B}$ :

$$\alpha_{A \rightarrow B} = \frac{\sum_j v_{B,j} D_{B,j} f_{BE}}{\sum_j v_{B,j} D_{B,j} f_{BE} + \sum_j v_{A,j} D_{A,j} f_{BE}}$$

# Solving for the average transmission coefficient

In the Debye model, the only difference in the density of state between material A and material B is the phonon group velocity. We can solve for  $\alpha_{A \rightarrow B}$ :

$$\alpha_{A \rightarrow B} = \frac{\sum_j v_{B,j}^{-2}}{\sum_j v_{B,j}^{-2} + \sum_j v_{A,j}^{-2}}$$

$$\tau_{A \rightarrow B,j} = \int_0^{\pi/2} \alpha_{A \rightarrow B,j}(\theta) \cos(\theta) \sin(\theta) d\theta$$

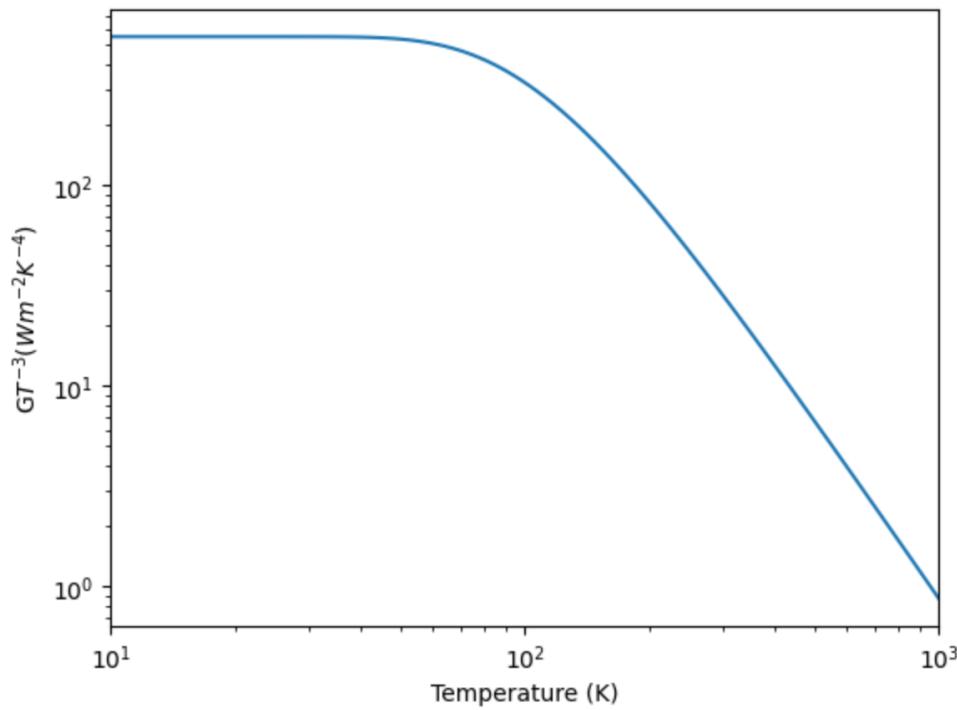
Since  $\alpha_{A \rightarrow B}$  is independent of  $\theta_A$ , so the angle integral becomes 1/2:

$$\tau_{A \rightarrow B} = \frac{1}{2} \frac{\sum_j v_{B,j}^{-2}}{\sum_j v_{B,j}^{-2} + \sum_j v_{A,j}^{-2}}$$

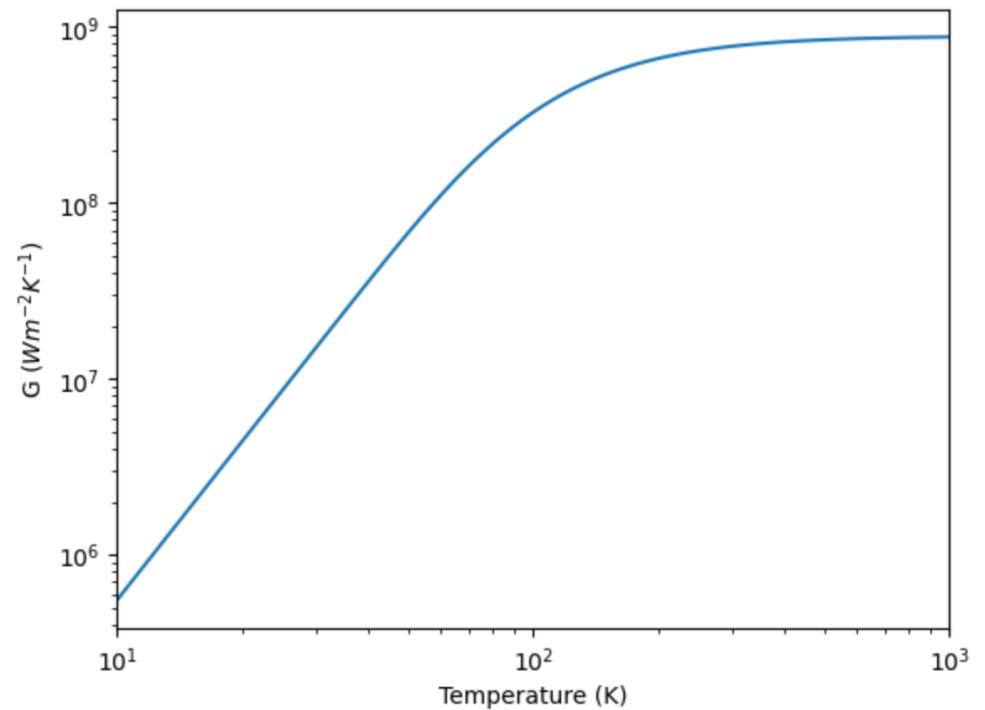
$$G = \frac{\tau_{A \rightarrow B} k_B^4 T^3}{4\pi^2 \hbar^3} \left[ \frac{1}{v_{A,l}^2} + \frac{2}{v_{A,t}^2} \right] \int_0^{x_D} x^4 \frac{e^x}{(e^x - 1)^2} dx$$

# Temperature dependent DMM

$$\int_0^{x_D} x^4 \frac{e^x}{(e^x - 1)^2} dx$$



$$G = \frac{\tau_{A \rightarrow B} k_B^4 T^3}{4\pi^2 \hbar^3} \left[ \frac{1}{v_{A,l}^2} + \frac{2}{v_{A,t}^2} \right] \int_0^{x_D} x^4 \frac{e^x}{(e^x - 1)^2} dx$$



# For a solid-solid interface, AMM and DMM is similar

Gold to Sapphire Interface

```
T = 10; # Kelvin
g_go_sa= g_AMM(gold.v_l, sapphire.v_l, gold.v_t, sapphire.v_t, gold.density, sapphire.density
g_go_sa_T = g_go_sa/T**3;
print(f"Gold to sapphire interface: {g_go_sa_T:.2f} W/m^2/K^4")
```

Gold to sapphire interface: 526.39 W/m^2/K^4

Gold to Quartz Interface

```
g_go_qz= g_AMM(gold.v_l, quartz.v_l, gold.v_t, quartz.v_t, gold.density, quartz.density
g_go_qz_T = g_go_qz/T**3;
print(f"Gold to Quartz interface: {g_go_qz_T:.2f} W/m^2/K^4")
```

Gold to Quartz interface: 1327.14 W/m^2/K^4

Gold to Silicon Interface

```
g_go_si= g_AMM(gold.v_l, silicon.v_l, gold.v_t, silicon.v_t, gold.density, silicon.density
g_go_si_T = g_go_si/T**3;
print(f"Gold to Silicon interface: {g_go_si_T:.2f} W/m^2/K^4")
```

Gold to Silicon interface: 780.96 W/m^2/K^4

Gold to Sapphire Interface

```
T = 10
g_go_sa= g_DMM_Tind(gold.v_l, sapphire.v_l, gold.v_t, sapphire.v_t, T_debye, T, 1000)
print(f"Gold to sapphire interface: {g_go_sa:.2f} W/m^2/K^4")
```

Gold to sapphire interface: 551.75 W/m^2/K^4

Gold to Quartz Interface

```
g_go_qz= g_DMM_Tind(gold.v_l, quartz.v_l, gold.v_t, quartz.v_t, T_debye, T, 1000)
print(f"Gold to Quartz interface: {g_go_qz:.2f} W/m^2/K^4")
```

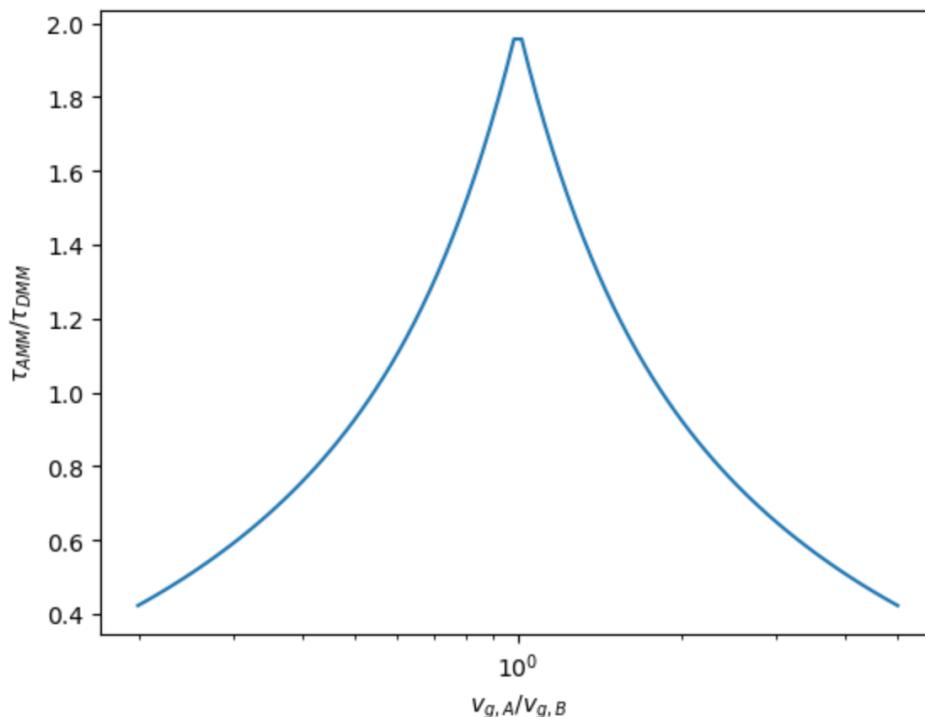
Gold to Quartz interface: 1336.20 W/m^2/K^4

Gold to Quartz Interface

```
g_go_si= g_DMM_Tind(gold.v_l, silicon.v_l, gold.v_t, silicon.v_t, T_debye, T, 1000)
print(f"Gold to Silicon interface: {g_go_si:.2f} W/m^2/K^4")
```

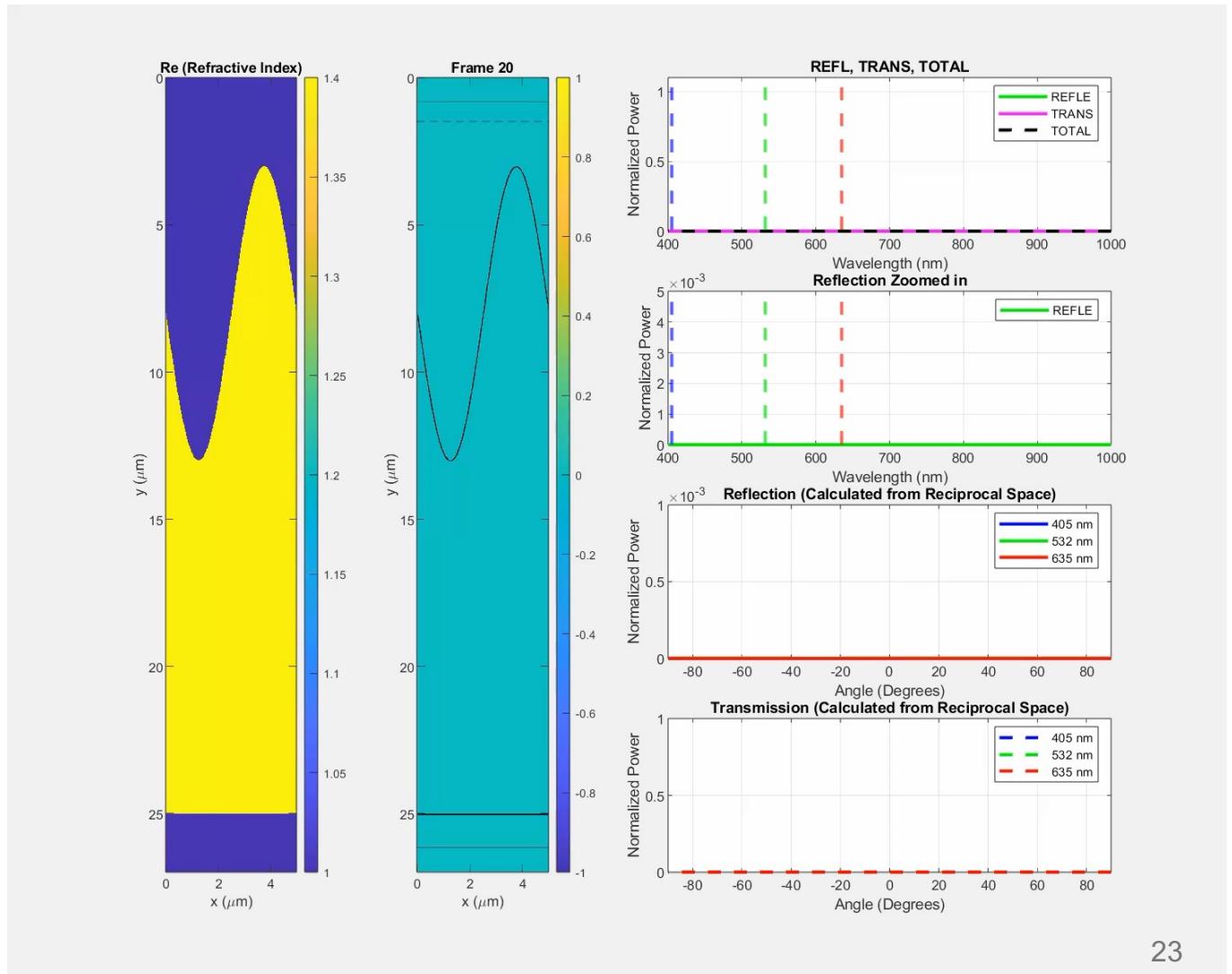
Gold to Silicon interface: 792.78 W/m^2/K^4

# Why does DMM and AMM is different



This result shows that when two materials are very similar, the  $\tau_{AMM} > \tau_{DMM}$ . However, whenever the group velocity varies dramatically,  $\tau_{AMM} < \tau_{DMM}$ . For most of the solid-solid interfaces, the phonon group velocity is so different that the transmission is significantly different.

# Questions



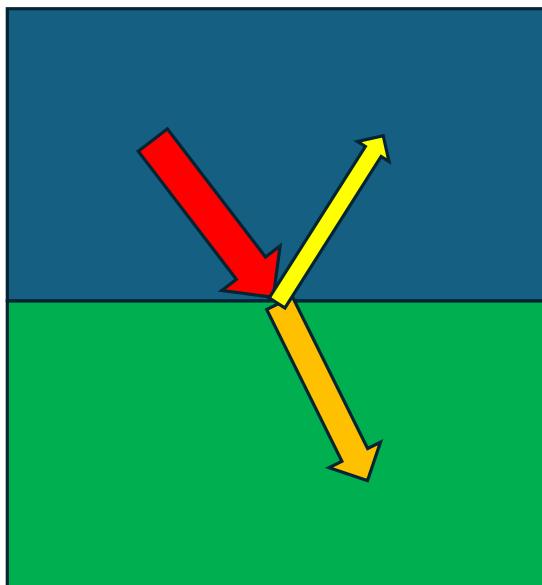
# Additional Slides

# Phononic window plot

$$f_{BE}(T_A, \omega) - f_{BE}(T_B, \omega) = \frac{\partial f_{BE}(T_A, \omega)}{\partial T} \Delta T$$

# Phonons is analogous to photons

## Acoustic Mismatch Model (AMM):



- Photons and phonons are both bosonic particles which follows the same Bose – Einstein distribution.
- Under Debye approximation, both photons and phonons follow the same density of states.

## Photon's behavior at the interface under specular reflection:

1. Photon's specular reflection and transmission of an interface can be derived from Maxwell's equations.
2. The derivations will not be shown here, due to time limitations. However, it is known as **Fresnel's equation**.
3. Fresnel's equation says:  
Transmission is dependent on the **angle** of the incident light, **polarization**, and the **refractive index** (optical impedance) of the two media.

# Fresnel Equation (Photons)

All these equations can be derived; They are **NOT** constitutive equations.  
They are derived from Maxwell's equation with proper boundary conditions at the interfaces.

$$R_s = \left| \frac{Z_2 \cos(\theta_i) - Z_1 \cos(\theta_t)}{Z_2 \cos(\theta_i) + Z_1 \cos(\theta_t)} \right|^2 \quad T_s = 1 - R_s$$

$$R_p = \left| \frac{Z_2 \cos(\theta_t) - Z_1 \cos(\theta_i)}{Z_2 \cos(\theta_t) + Z_1 \cos(\theta_i)} \right|^2 \quad T_p = 1 - R_p$$

Wave Impedance:

$$Z_1 = \frac{Z_0}{n_1}, Z_2 = \frac{Z_0}{n_2}$$

Snell's Law:

$$\frac{\sin(\theta_i)}{n_1} = \frac{\sin(\theta_t)}{n_t}$$

# Phonon simplifications

Phonon branches are derived from the theory of elasticity which is very different E&M:

- Simplification 1:  
We are only

$$R_s = \left| \frac{Z_2 \cos(\theta_i) - Z_1 \cos(\theta_t)}{Z_2 \cos(\theta_i) + Z_1 \cos(\theta_t)} \right|^2$$

# Phonons are different from photons (branches)

Phonon branches are derived from the theory of elasticity which is very different E&M.

- This result that phonons has three branches rather than two polarizations; We have to significantly simplify it to grasp basic understanding.
- This assumption does not allow total internal reflection. However, it is a huge simplification but necessary.

$$\tau_{A \rightarrow B}(\omega) = \tau_{B \rightarrow A}(\omega)$$

$$R_s = \left| \frac{Z_2 \cos(\theta_i) - Z_1 \cos(\theta_t)}{Z_2 \cos(\theta_i) + Z_1 \cos(\theta_t)} \right|^2$$